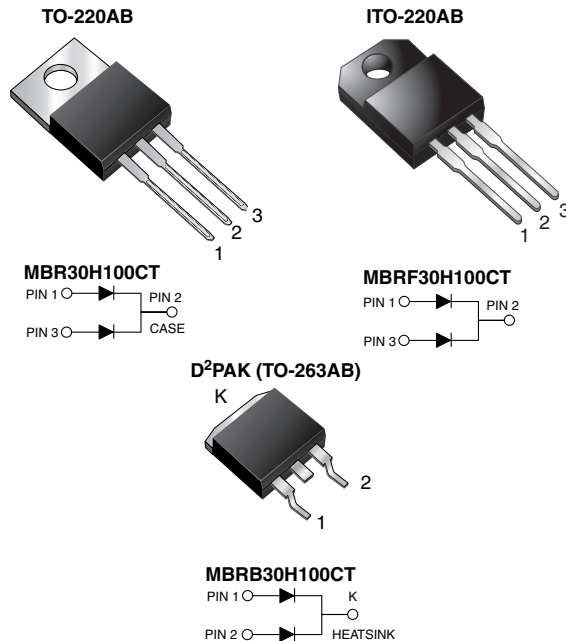


**Dual Common Cathode High Voltage Schottky Rectifier**

High Barrier Technology for Improved High Temperature Performance

**FEATURES**

- Power pack
- Guardring for overvoltage protection
- Low power loss, high efficiency
- Low forward voltage drop
- Low leakage current
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C for D<sup>2</sup>PAK (TO-263AB) package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB and ITO-220AB package)
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)

**RoHS**  
COMPLIANT  
**HALOGEN**  
**FREE**  
Available**TYPICAL APPLICATIONS**

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, and polarity protection application.

**MECHANICAL DATA****Case:** TO-220AB, ITO-220AB, D<sup>2</sup>PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-E3 - RoHS-compliant, commercial grade

Base P/N-M3 - RoHS-compliant, Halogen free, commercial grade

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 and M3 suffix meets JESD 201 class 1A whisker test

**Polarity:** As marked**Mounting Torque:** 10 in-lbs maximum**LINKS TO ADDITIONAL RESOURCES**

PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	2 x 15 A
$V_{RRM}$	100 V
$I_{FSM}$	275 A
$V_F$	0.67 V
$I_R$	5.0 $\mu$ A
$T_J$ max.	175 °C
Package	TO-220AB, ITO-220AB, D <sup>2</sup> PAK (TO-263AB)
Circuit configuration	Common cathode

**MAXIMUM RATINGS** ( $T_C = 25$  °C unless otherwise noted)

PARAMETER	SYMBOL	MBR30H100CT MBRF30H100CT MBRB30H100CT	UNIT
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	100	V
Working peak reverse voltage	V <sub>RWM</sub>	100	
Maximum DC blocking voltage	V <sub>DC</sub>	100	
Maximum average forward rectified current (fig.1)	total device	30	A
	per diode	15	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I <sub>FSM</sub>	275	
Peak repetitive reverse surge current per diode at t <sub>p</sub> = 2.0 μs, 1 kHz	I <sub>RRM</sub>	1.0	
Voltage rate of change (rated V <sub>R</sub> )	dV/dt	10 000	
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	-65 to +175	°C
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min	V <sub>AC</sub>	1500	V



# MBR30H100CT, MBRF30H100CT, MBRB30H100CT

[www.vishay.com](http://www.vishay.com)

Vishay General Semiconductor

ELECTRICAL CHARACTERISTICS ( $T_C = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUE	UNIT
Maximum instantaneous forward voltage per diode	$V_F$ (1)	$I_F = 15\text{ A}$	$T_J = 25\text{ }^{\circ}\text{C}$	0.82	V
		$I_F = 15\text{ A}$	$T_J = 125\text{ }^{\circ}\text{C}$	0.67	
		$I_F = 30\text{ A}$	$T_J = 25\text{ }^{\circ}\text{C}$	0.93	
		$I_F = 30\text{ A}$	$T_J = 125\text{ }^{\circ}\text{C}$	0.80	
Maximum reverse current per diode	$I_R$ (2)	Rated $V_R$	$T_J = 25\text{ }^{\circ}\text{C}$	5.0	$\mu\text{A}$
			$T_J = 125\text{ }^{\circ}\text{C}$	6.0	mA

## Note

(1) Pulse test: 300  $\mu\text{s}$  pulse width, 1 % duty cycle

(2) Pulse test: Pulse width,  $\leq 40\text{ ms}$

THERMAL CHARACTERISTICS ( $T_C = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)					
PARAMETER	SYMBOL	MBR30H100CT	MBRF30H100CT	MBRB30H100CT	UNIT
Typical thermal resistance per diode	$R_{\theta JC}$	1.9	4.6	1.9	$^{\circ}\text{C/W}$

ORDERING INFORMATION					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-220AB	MBR30H100CT-E3/45	1.85	45	50/tube	Tube
ITO-220AB	MBRF30H100CT-E3/45	1.99	45	50/tube	Tube
D <sup>2</sup> PAK (TO-263AB)	MBRB30H100CT-M3/I	1.35	I	800/reel	Tape and reel



## RATINGS AND CHARACTERISTICS CURVES ( $T_C = 25^\circ\text{C}$ unless otherwise noted)

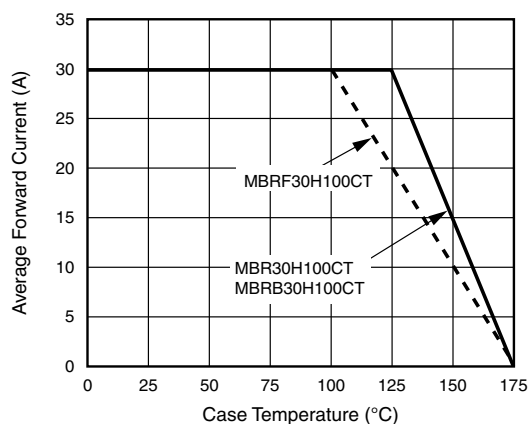


Fig. 1 - Forward Derating Curve Per Diode

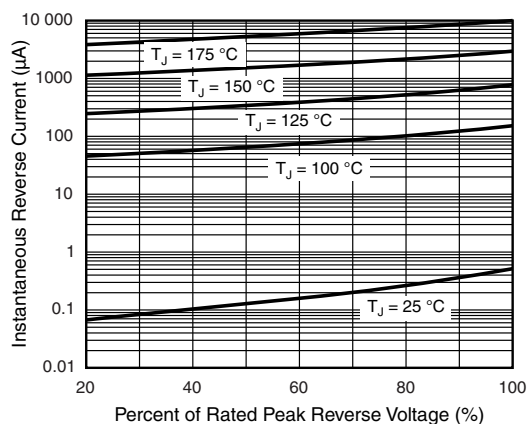


Fig. 4 - Typical Reverse Characteristics Per Diode

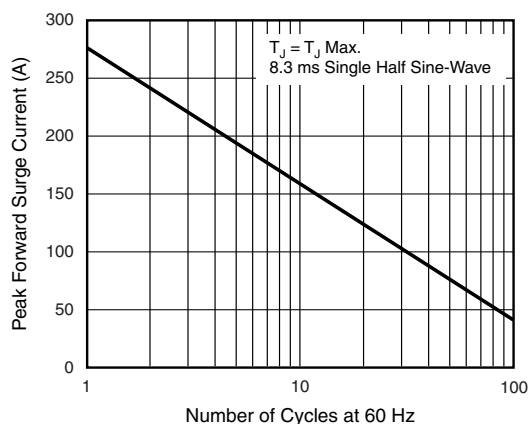


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

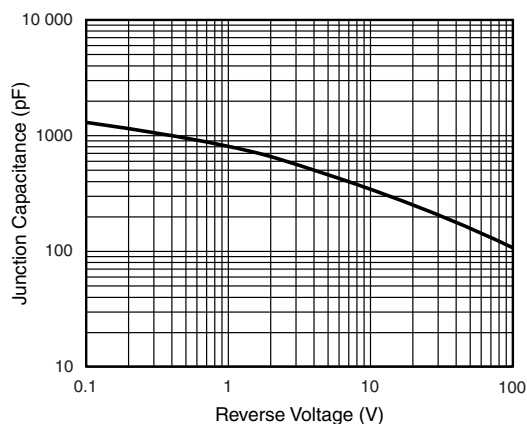


Fig. 5 - Typical Junction Capacitance Per Diode

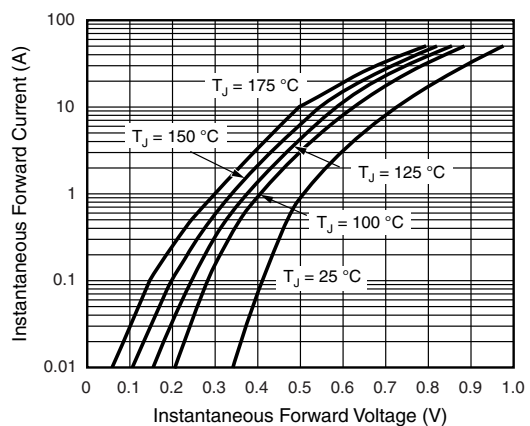


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

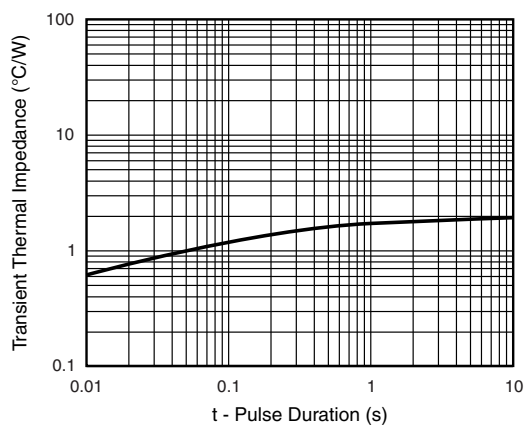
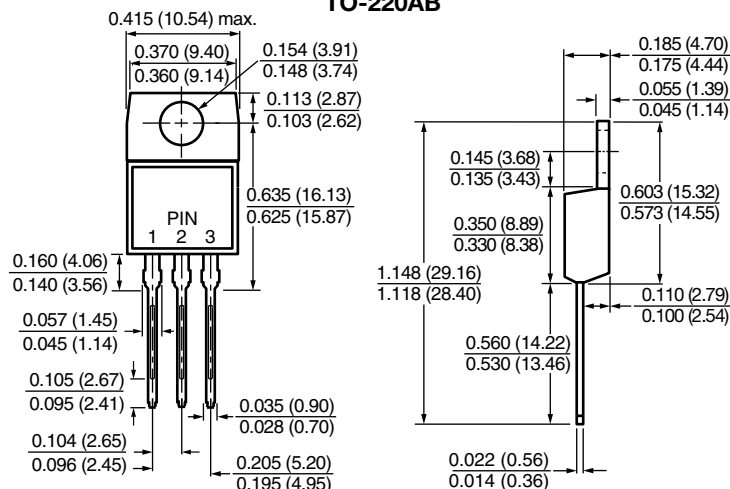


Fig. 6 - Typical Transient Thermal Impedance Per Diode

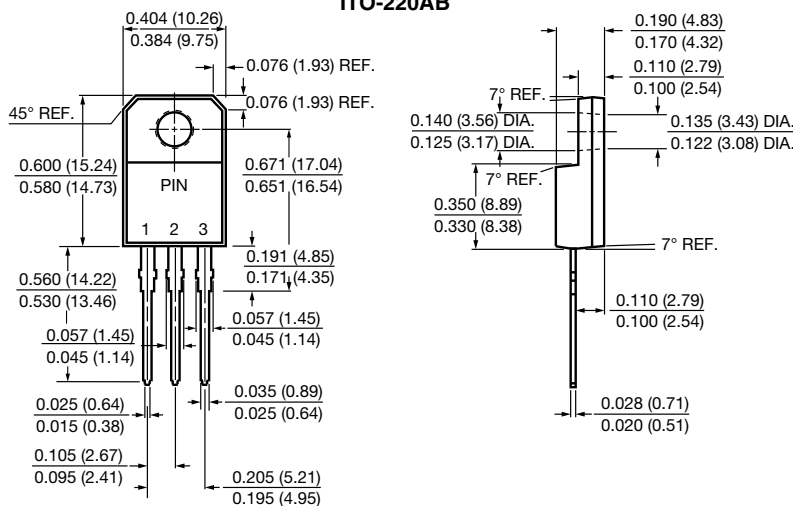


## PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

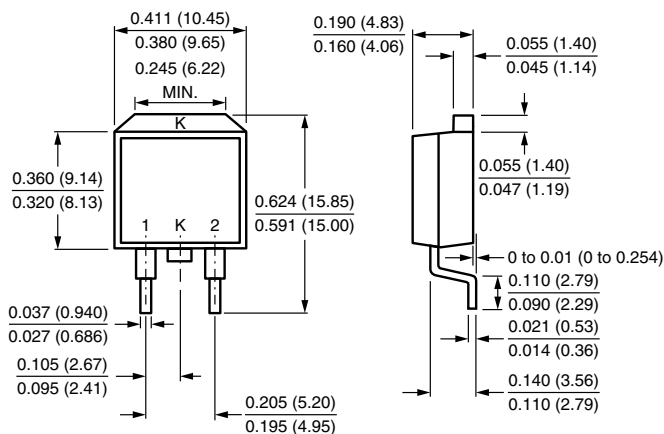
### TO-220AB



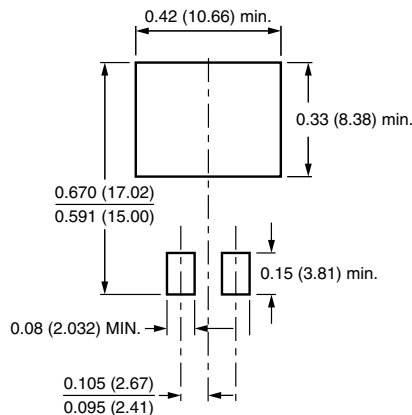
### ITO-220AB



### D<sup>2</sup>PAK (TO-263AB)



### Mounting Pad Layout





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